UNISONIC TECHNOLOGIES CO., LTD

UT4822 Power MOSFET

DUAL N-CHANNEL ENHANCEMENT MODE

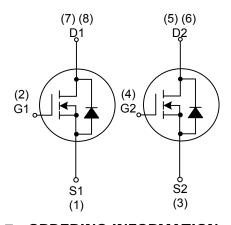
■ DESCRIPTION

The **UT4822** can provide excellent $R_{DS(ON)}$ and low gate charge by using advanced trench technology. The **UT4822** is suitable for using as a load switch or in PWM applications.

■ FEATURES

- * 30V/8.5A
- * Low $R_{DS(ON)}$
- * Reliable and Rugged

■ SYMBOL



SOP-8 1 tree 1

■ ORDERING INFORMATION

Note: Pin Assignment: G: Gate

Ordering Number		Daakaga	Pin Assignment							Dooking	
Lead Free	Halogen Free	Package –		2	3	4	5	6	7	8	Packing
UT4822L-S08-R	UT4822G-S08-R	SOP-8	S1	G1	S2	G2	D2	D2	D1	D1	Tape Reel
UT4822L-P3030-R	UT4822G-P3030-R	PDFN3×3	S1	G1	S2	G G	D2	D2	D1	D1	Tape Reel
UT4822L-P5060-R	UT4822G-P5060-R	PDFN5×6	S1	G1	S2	G2	D2	D2	D1	D1	Tape Reel

S: Source

D: Drain

UT4822G-S08-R
(1)Packing Type
(1) R: Tape Reel
(2) S08: SOP-8, P3030: PDFN3×3, P5060: PDFN5×6
(3)Green Package
(3) G: Halogen Free and Lead Free, L: Lead Free

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■ MARKING

PACKAGE	MARKING							
SOP-8	Date Code UTC UT4422 CHAPTER STREET UT4422 CHAPTER STREET L: Lead Free G: Halogen Free Lot Code							
PDFN3×3	UT 4422 • □□□□ Date Code							
PDFN5×6	UTC UT 4422 Lot Code Date Code							

UT4822 Power MOSFET

■ **ABSOLUTE MAXIMUM RATINGS** (T_A = 25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DS}	30	V
Gate-Source Voltage		V_{GS}	±20	>
Continuous Drain Current		I_{D}	8.5	Α
Pulsed Drain Current		I _{DM}	40	Α
Power Dissipation (T _C =25°C)	SOP-8	P _D	1.2	W
	PDFN3×3		20	W
	PDFN5×6		22	W
Junction Temperature		TJ	+150	°C
Storage Temperature		T _{STG}	-55 ~ + 150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	SOP-8	θја	125	°C/W
	PDFN3×3		75	°C/W
	PDFN5×6		65	°C/W
Case to Ambient	SOP-8	$ heta_{ extsf{JC}}$	104	°C/W
	PDFN3×3		6.25	°C/W
	PDFN5×6		5.6	°C/W

Note: Device mounted on FR-4 substrate Pc board, 2oz copper, with 1inch square copper plate.

^{2.} Repetitive Rating: Pulse width limited by maximum junction temperature.

■ **ELECTRICAL CHARACTERISTICS** (T_A =25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT			
OFF CHARACTERISTICS									
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	30			V			
Drain-Source Leakage Current	I _{DSS}	V _{DS} =24V, V _{GS} =0V			1	uA			
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA			
ON CHARACTERISTICS									
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}$, $I_D=250uA$	1.0		3.0	V			
Drain Cauras On Ctata Basistanas	R _{DS(ON)}	V _{GS} =10V, I _D =8.5A		16	19	mΩ			
Drain-Source On-State Resistance		V _{GS} =4.5V, I _D =6.0A		21	26	mΩ			
DYNAMIC CHARACTERISTICS									
Input Capacitance	C _{ISS}			560		pF			
Output Capacitance	Coss	V _{GS} =0V,V _{DS} =15V,f=1.0MHz		150		pF			
Reverse Transfer Capacitance	C _{RSS}			140		pF			
SWITCHING CHARACTERISTICS			_						
Total Gate Charge	Q_G	V 04V V 40V L 0.5A		23		nC			
Gate-Source Charge	Q_{GS}	V _{DS} =24V, V _{GS} =10V, I _D =8.5A (Note 1. 2)		2.5		nC			
Gate-Drain Charge	Q_GD	(Note 1, 2)		6		nC			
Turn-ON Delay Time	t _{D(ON)}			6		ns			
Turn-ON Rise Time	t _R	V_{DD} =15V, V_{GS} =10V, I_{D} =8.5A		16		ns			
Turn-OFF Delay Time	t _{D(OFF)}	R _G =3Ω (Note 1, 2)		18		ns			
Turn-OFF Fall Time	t _F			24		ns			
SOURCE- DRAIN DIODE RATINGS AND	CHARACTE	RISTICS		-	-				
Maximum Continuous Drain-Source Diode					8.5	Α			
Forward Current	I _S				6.5	A			
Maximum Pulsed Drain-Source Diode	I _{SM}				40	Α			
Forward Current	ISM				40	Α			
Drain-Source Diode Forward Voltage	V_{SD}	I _S =1A, V _{GS} =0V		0.76	1.0	V			
Reverse Recovery Time	t _{rr}	I _F =8.5A, dI _F /dt=100A/μs		480		ns			
Reverse Recovery Charge	Q _{rr}			7		μC			

Notes: 1. Pulse Test : Pulse width ≤ 300µs, Duty cycle ≤ 2%.

^{2.} Essentially independent of operating temperature.

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